

Revision 0.53

## **SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser**



General	Product	Information

Application
Spectroscopy
Metrology
Magnetometer



## Absolute Maximum Ratings

Parameter	Symbol	Unit	min	typ	max
Storage Temperature	Ts	°C	-40		85
Operational Temperature at Case	$T_{C}$	°C	-40		85
Operational Temperature at Laser Chip	$T_{LD}$	°C	10		50
Forward Current	I <sub>F</sub>	mA			200
Reverse Voltage	$V_R$	V			2
Output Power	$P_{opt}$	mW			90
TEC Current	I <sub>TEC</sub>	Α			1.1
TEC Voltage	$V_{TEC}$	V			2.8

#### **Measurement Conditions / Comments**

Stress in excess of one of the Absolute Maximum Ratings may damage the laser. Please note that a damaging optical power level may occur although the maximum current is not reached. These are stress ratings only, and functional operation at these or any other conditions beyond those indicated under Recommended Operational Conditions is not implied.

### Recommended Operational Conditions

Parameter	Symbol	Unit	min	typ	max
Operational Temperature at Case	$T_{case}$	°C	-20		65
Operational Temperature at Laser Chip	$T_LD$	°C	15		40
Forward Current	I <sub>F</sub>	mA			190
Output Power	$P_{\text{opt}}$	mW	20		80

Measurement Conditions / Comments
measured by integrated Thermistor

### Characteristics at T<sub>LD</sub> = 25° at BOL

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	$\lambda_{C}$	nm	1082	1083	1084
Linewidth (FWHM)	$\Delta\lambda$	MHz		2	
Mode-hop free Tuning Range	$\Delta \lambda_{\text{tune}}$	pm	#NV	#NV	#NV
Sidemode Supression Ratio	SMSR	dB	30	45	
Temperature Coefficient of Wavelength	dλ / dT	nm / K		0.06	
Current Coefficient of Wavelength	dλ / dI	nm / mA		0.003	

Measurement Conditions / Comments
see images on page 4
$P_{opt} = 80 \text{ mW}$
#NV
$P_{opt} = 80 \text{ mW}$



Revision 0.53

# **SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser**



Characteristics at T <sub>LD</sub> = 25° a	at BOL				cont'd
Parameter	Symbol	Unit	min	typ	max
Mode-hop free Temperature Range	$T_{LD}$	° C	#NV	#NV	#NV
Mode-hop free Power Range	P <sub>opt</sub>	mW	#NV	#NV	#NV
Laser Current @ P <sub>opt</sub> = 80 mW	I <sub>LD</sub>	mA			190
Slope Efficiency	η	W/A	0.6	0.8	1.0
Threshold Current	I <sub>th</sub>	mA			70
Divergence parallel (FWHM)	$\Theta_{  }$	o		0.1	
Divergence perpendicular (FWHM)	$\Theta_{\perp}$	0		0.1	
Beam Diameter horizontal (1/e²)	d	mm		1.0	1.2
Beam Diameter vertical (1/e²)	$d_\perp$	mm		0.8	1.2
Degree of Polarization	DOP	%		90	

#NV					
#NV					
parallel	to the bas	e plate (	of the ho	ousing (se	ee p. 3)
perpend	icular to b	ase plat	e of the	housing	(see p. 3
parallel	to the bas	e plate o	of the ho	ousing (se	ee p. 3)
perpend	icular to b	ase plat	e of the	housing	(see p. 3
90 m\//·	E field par	allel to	the base	nlate	

Monitor Diode					
Parameter	Symbol	Unit	min	typ	max
Monitor Detector Responsivity	I <sub>mon</sub> / P <sub>opt</sub>	μA/mW	0.05		10

$U_R = 5 \text{ V}$	Meası	urement Conditions / Comments
	$U_R =$	5 V

Symbol	Unit	min	typ	max
I <sub>TEC</sub>	А		0.4	
$U_TEC$	V		0.8	
P <sub>loss</sub>	W		0.4	
ΔΤ	K			50
	I <sub>TEC</sub> U <sub>TEC</sub> P <sub>loss</sub>	I <sub>TEC</sub> A U <sub>TEC</sub> V P <sub>loss</sub> W	I <sub>TEC</sub> A U <sub>TEC</sub> V P <sub>loss</sub> W	I <sub>TEC</sub> A 0.4 U <sub>TEC</sub> V 0.8 P <sub>loss</sub> W 0.4

Measurement Conditions / Comments				
P <sub>opt</sub> =	80 mW, Δ	$\Gamma = 20 \text{ K}$		
P <sub>opt</sub> =	80 mW, Δ	Γ = 20 K		
P <sub>opt</sub> =	80 mW, Δ	Γ = 20 K		
P <sub>opt</sub> =	80 mW, Δ	Γ =  Tcas	e - TLD	

Thermistor (Standard NTC Type)						
Parameter	Symbol	Unit	min	typ	max	
Resistance	R	kΩ		10		
Beta Coefficient	β			3892		
Steinhart & Hart Coefficient A	А		1.1293 x 10 <sup>#NV</sup>			
Steinhart & Hart Coefficient B	В		2.3410 x 10 <sup>#NV</sup>			
Steinhart & Hart Coefficient C	C			8.7755 x 10	#NV	

Measurement Conditions / Comments				
$T_{LD} = 25^{\circ} C$				
$R_1  /  R_2 = e^{ \beta  (1/T_1  -  1/T_2)} $ at $T_{LD} =$	0° 50° C			
$1/T = A + B(\ln R) + C(\ln R)^3$				
T: temperature in Kelvin				
R: resistance at T in Ohm				



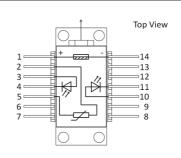
Revision 0.53

## **SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser**

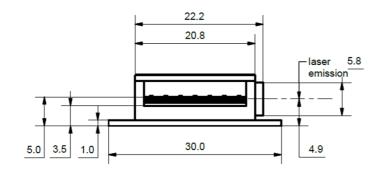


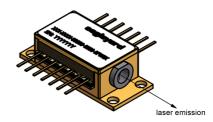
## Pin Assignment

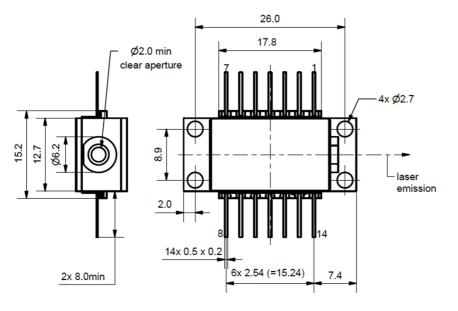
1	Thermoelectric Cooler (+)	14	Thermoelectric Cooler (-)		
2	Thermistor	13	Case		
3	Photodiode (Anode)	12	not connected		
4	Photodiode (Cathode)	11	Laser Diode (Cathode)		
5	Thermistor	10	Laser Diode (Anode)		
6	not connected	9	not connected		
7	not connected	8	not connected		
Pins are isolated from case unless noted otherwise.					



### Package Drawings







Caution. Excessive mechanical stress on the package can lead to a damage of the laser.

See <u>instruction manual</u> on www.eagleyard.com

AIZ-20-1029-0928



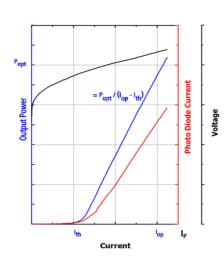
Revision 0.53

## SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser

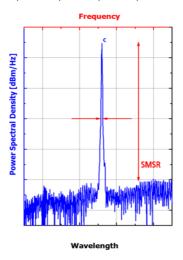


#### Typical Measurement Results

Output Power vs. Current



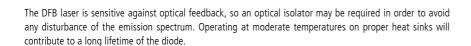
Spectra at Specified Optical Output Power



Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

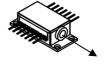
#### Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.



Avoid direct and/or indirect exposure to the free running beam. Collimating and focussing the free running beam with optics as common in optical instruments will increase threat to the human eye.

Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.







Laser Emission

INVISIBLE LASER RADIATION
AVOID EYE OR SKIN EXPOSURE
TO DIRECT OR SCATTERED RADIATION
CLASS 4 LASER PRODUCT
WAYELENGTH 1083 nm
MAX. OUTPUT POWER 90 mW



